Ordering number : ENA0113



SANYO Semiconductors DATA SHEET

VEC2307

P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- · The best suited for load switches.
- · Composite type, facilitaing high-density mounting.
- · Mount height 0.75mm.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS	- MIN -	-30	V
Gate-to-Source Voltage	VGSS	VIII COM	±20	V
Drain Current (DC)	ID	40.00	-2	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-8	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm²X0.8mm)1unit	0.9	W
Total Dissipation	PT	Mounted on a ceramic board (900mm²X0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-1A	1.2	2.0		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-1A, VGS=-10V		130	170	mΩ
	R _{DS} (on)2	I _D =-0.5A, V _G S=-4V		225	320	mΩ
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		200		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		47	W.	pF
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		32	0750	pF

Marking: CH

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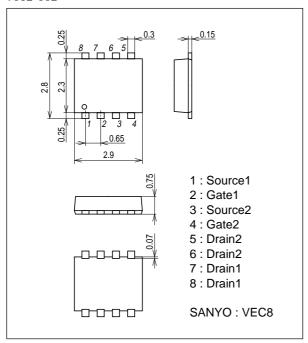
VEC2307

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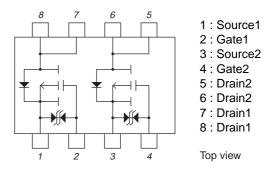
Parameter	Cumbal	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		7.2		ns
Rise Time	t _r	See specified Test Circuit.		2.9		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		21		ns
Fall Time	tf	See specified Test Circuit.		8.7		ns
Total Gate Charge	Qg	V _{DS} =-10V, V _{GS} =-10V, I _D =-2A		5.5		nC
Gate-to-Source Charge	Qgs	V _{DS} =-10V, V _{GS} =-10V, I _D =-2A		0.98		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-10V, V _{GS} =-10V, I _D =-2A		0.82		nC
Diode Forward Voltage	V _{SD}	IS=-2A, VGS=0V		-0.85	-1.5	V

Package Dimensions

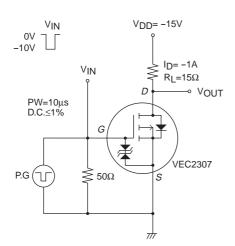
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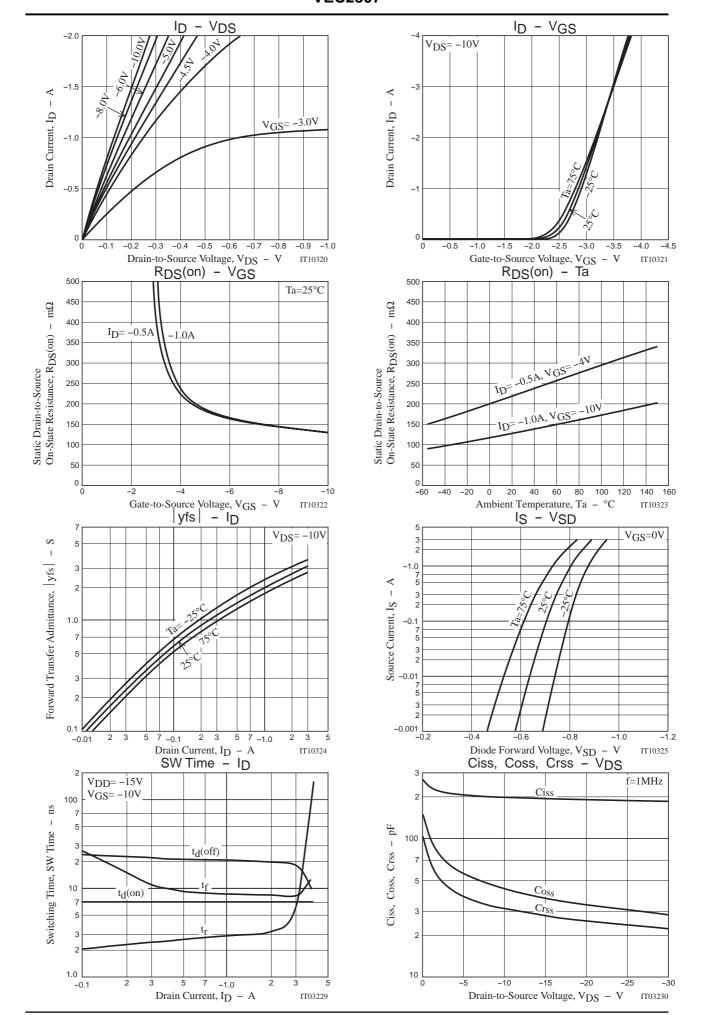


Electrical Connection

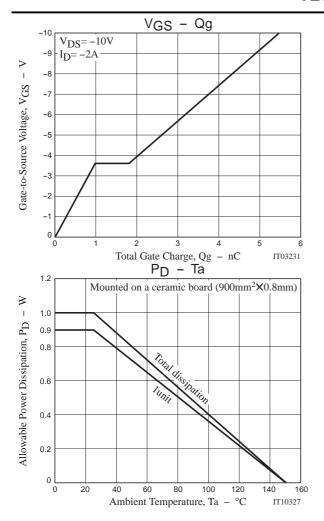


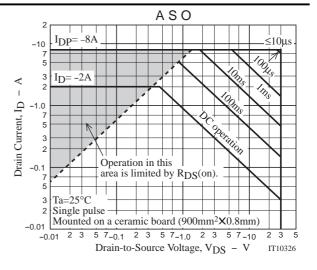
Switching Time Test Circuit





VEC2307





Note on usage : Since the VEC2307 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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